√RoHS

Analog Dual Axis Micromachined Accelerometer

The MMA62XXAKEG series of dual axis (X and Y) silicon capacitive, micromachined accelerometers features a full digital signal processing for filtering, trim and data formatting. It has been optimized for analog output and offers an over-damped transducer.

Features

- Available in ±20/20g, ±50/50g, or ±100/100g versions. Additional g-ranges between 20 and 100g may be available upon request
- · Full-scale range is independently specified for each axis
- 400 Hz, 4 Pole, 16 μs sample time, additional filter options are available
- Ratiometric analog voltage output
- · Capture/hold input for system-wide synchronization support
- · 3.3 or 5 V single supply operation
- On-chip temperature sensor and voltage regulator
- · Internal self-test
- Minimal external component requirements
- Pb-free 20-pin SOIC package
- Qualified AEC-Q100, Rev. F Grade 2 (-40°C/+105°C)

Typical Applications

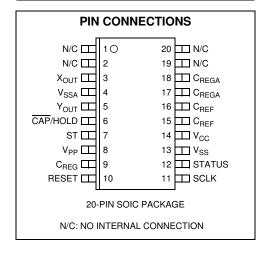
- · Crash Detection (Airbag)
- · Impact and vibration monitoring
- · Shock detection

MMA6222AKEG MMA6255AKEG MMA621010AKEG

2-AXIS ACCELEROMETER



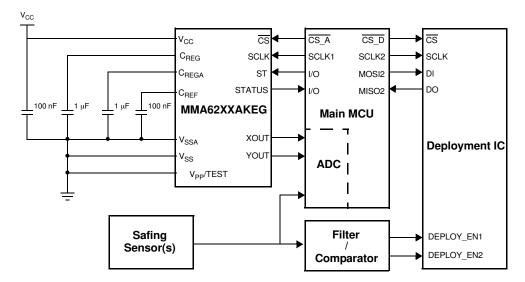
KEG SUFFIX (Pb-free) 20-LEAD SOIC CASE 475A-02



| ORDERING INFORMATION | | | | | | | | |
|----------------------|----------------|----------------|-------------------|---------|-------------|--|--|--|
| Device Name | X-Axis g-Level | Y-Axis g-Level | Temperature Range | Package | Packaging | | | |
| MMA6222AEG | 20 | 20 | -40 to +105℃ | 475A-02 | Tubes | | | |
| MMA6222AEGR2 | 20 | 20 | -40 to +105℃ | 475A-02 | Tape & Reel | | | |
| MMA6222AKEG* | 20 | 20 | -40 to +105℃ | 475A-02 | Tubes | | | |
| MMA6222AKEGR2* | 20 | 20 | -40 to +105℃ | 475A-02 | Tape & Reel | | | |
| MMA6255AEG | 50 | 50 | -40 to +105℃ | 475A-02 | Tubes | | | |
| MMA6255AEGR2 | 50 | 50 | -40 to +105℃ | 475A-02 | Tape & Reel | | | |
| MMA6255AKEG* | 50 | 50 | -40 to +105℃ | 475A-02 | Tubes | | | |
| MMA6255AKEGR2* | 50 | 50 | -40 to +105℃ | 475A-02 | Tape & Reel | | | |
| MMA621010AEG | 100 | 100 | -40 to +105℃ | 475A-02 | Tubes | | | |
| MMA621010AEGR2 | 100 | 100 | -40 to +105℃ | 475A-02 | Tape & Reel | | | |
| MMA621010AKEG* | 100 | 100 | -40 to +105℃ | 475A-02 | Tubes | | | |
| MMA621010AKEGR2* | 100 | 100 | -40 to +105℃ | 475A-02 | Tape & Reel | | | |

^{*}Part number sourced from a different facility.





Note: If one axis of the MMA62XXAKEG sensor is expected to be used as a confirmation of the other axis, Freescale recommends that MMA62XXAKEG used in conjunction with an additional sensing/safing device for each axis.

Figure 1-1 Simplified Airbag Application Diagram

1.1 INTRODUCTION

The MMA62XXKEG is trimmed to provide the most accurate voltage representation of acceleration at X_{OUT} and Y_{OUT} . This is done by adjusting the signal within the DSP to compensate for errors within the digital-to-analog converters. The SPI is disabled when the device is in normal operating mode, and dedicated ST (self-test activation) and STATUS pin functions are assigned.

1.2 BLOCK DIAGRAM

A block diagram illustrating the major components of the design is shown in Figure 1-2.

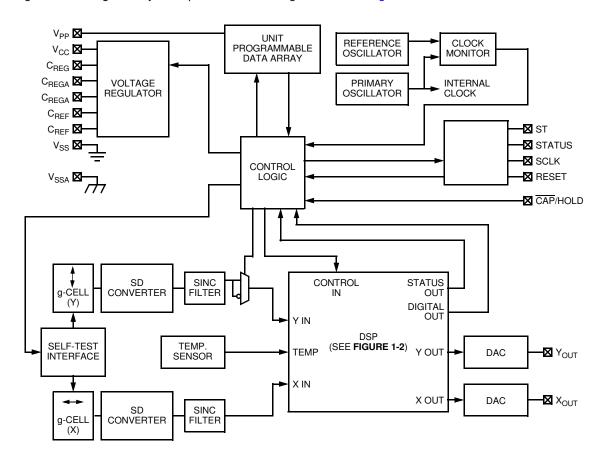


Figure 1-2 MMA62XXAKEG Block Diagram

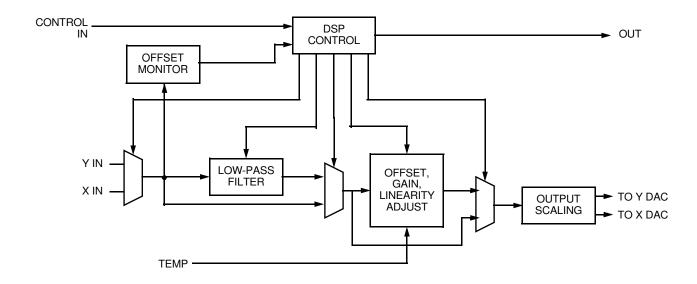
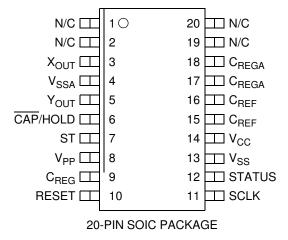


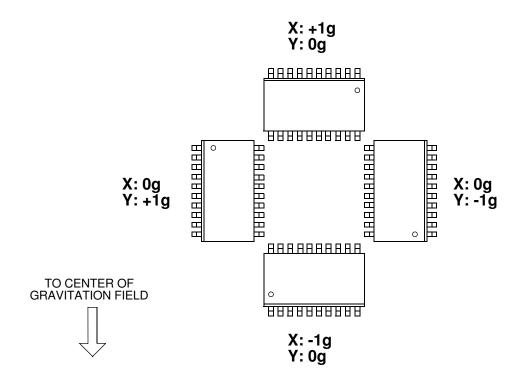
Figure 1-3 MMA62XXAKEG DSP Block Diagram NOTE: Models of signal chain are available upon request

1.3 PIN FUNCTIONS

The pinout for the MMA62XXAKEG device is illustrated in Figure 1-4. Pin functions are described below. When self-test is active, the output becomes more positive in both axes if ST1 is cleared, or more negative in both axes if ST1 is set.



N/C: NO INTERNAL CONNECTION



Response to static orientation within 1g field.

Figure 1-4 MMA62XXAKEG Pinout

1.4 PIN FUNCTION DESCRIPTIONS

1.4.1 V_{CC}

This pin supplies power to the device. Careful printed wiring board layout and capacitor placement is critical to ensure best performance. An external bypass capacitor between this pin and V_{SS} is required, as described in Section 1.5.

1.4.2 V_{SS}

This pin is the power supply return node for the digital circuitry on the MMA62XXKEG device.

1.4.3 V_{SSA}

This pin is the power supply return node for analog circuitry on the MMA62XXAKEG device. An external bypass capacitor between this pin and V_{CC} is required, as described in Section 1.5.

1.4.4 C_{REG}

This pin is connected to the internal digital circuitry power supply rail. An external filter capacitor must be connected between this pin and V_{SS} , as described in Section 1.5.

1.4.5 C_{REGA}

These pins are connected in parallel to the internal analog circuitry power supply rail. One or two external filter capacitors must be connected between these pins and $V_{\rm SSA}$, as described in Section 1.5. Two pins are provided to support redundant connection to the printed wiring board assembly. Redundant external capacitors may be connected to these pins for maximum reliability, as described in Section 1.5.

1.4.6 C_{REF}

These pins are connected in parallel to an internal reference voltage node utilized by the analog circuitry. One or two external filter capacitors must be connected between these pins and $V_{\rm SSA}$, as described shown in Section 1.5. Two pins are provided to support redundant connection to the printed wiring board assembly. Redundant external capacitors may be connected to these pins for maximum reliability, as described in Section 1.5.

1.4.7 VPP

This pin should be tied directly to V_{SS} .

1.4.8 SCLK

This input may be left unconnected unless it is desired to initiate device reset as described in Section 1.4.9.

1.4.9 **RESET**

This pin may be used to initiate a hardware reset. If RESET is held low and SCLK is held high for 512 μs, the internal reset signal is asserted.

An internal pull-up device is connected to this pin.

1.4.10 STATUS

This pin provides an indicator of internal status. The STATUS output will be driven to a logic high level should any of the following fault conditions be detected:

- · Internal parity fault
- Over-temperature condition
- · Internal clock frequency fault
- · Device reset
- · Device initialization

Immediately following device reset, STATUS is placed in a high impedance state for approximately $800 \, \mu s$. At the end of this time, STATUS is driven high and a 3ms stabilization delay required by the internal circuitry begins. The STATUS condition may not be cleared during the stabilization delay. Reset is reported by the device so the system can be aware of potential difficulties if unexpected resets occur.

Once asserted, the STATUS output will remain high until the ST pin is driven from a logic low to a logic high state. If a fault condition persists, the STATUS output will be driven high again as soon as it is cleared.

1.4.11 ST

This pin performs a dual function. When driven to a logic high level, the internal self-test voltage generator is activated. A low-to-high transition on this pin will clear the internal STATUS latch. Note that under certain fault conditions, the STATUS latch will be immediately reset, indicating a terminal fault condition.

A diagram illustrating operation of the STATUS latch following device initialization is illustrated in Figure 1-5.

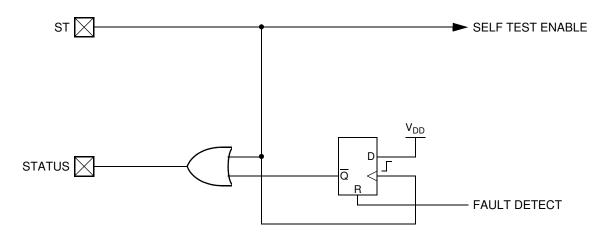


Figure 1-5 ST and STATUS Interaction

1.4.12 **CAP/HOLD**

When this input pin is low, acceleration data is updated by the DSP whenever a data sample becomes available. Upon a low-to-high transition of CAP/HOLD acceleration data is frozen. Acceleration data is not updated as long as the pin remains at a logic '1' level. This pin may be tied directly to V_{SS} if the hold function is not desired.

1.4.13 X_{OUT}, Y_{OUT}

Two digital-to-analog converters (DACs) are provided. These converters translate output of the DSP block into voltage levels proportional to the magnitude of the numerical result and ratiometric to V_{CC} .

1.5 EXTERNAL COMPONENTS

The connections illustrated in Figure 1-1 are recommended. Careful printed wiring board layout and component placement is essential for best performance. Low ESR capacitors must be connected to C_{REG} and C_{REGA} pins for the best performance. A grounded land area with solder mask should be placed under the package for improved shielding of the device from external effects. If a land area is not provided, no signals should be routed beneath the package. See Figure 1-1.

SECTION 2 PERFORMANCE SPECIFICATION

2.1 MAXIMUM RATINGS

Maximum ratings are the extreme limits to which the device can be exposed without permanently damaging it. The device contains circuitry to protect the inputs against damage from high static voltages; however, do not apply voltages higher than those shown in the table below. Keep input and output voltages within the range $V_{SS} \le V \le V_{CC}$.

| Ref | Rating | Symbol | Value | Unit |
|----------------|---|--|--|--------|
| 1 | Supply Voltage | V _{CC} | -0.3 to +7 | V |
| 2 | C _{REG} , C _{REGA} , C _{REF} | V _{REG} | -0.3 to +3 | V |
| 3 | V_{PP} | V _{REG} | -0.3 to +11 | V |
| 4 | SCLK, ST, CAP/HOLD | V _{IN} | -0.3 to V _{CC} + 0.3 | V |
| 5 | STATUS (high impedance state) | V _{IN} | V _{IN} -0.3 to V _{CC} + 0.3 | |
| 6 | X _{OUT} , Y _{OUT} (DACEN = 0) | V _{DAC} | V _{DAC} -0.3 to V _{CC} + 0.3 | |
| 7 | Current Drain per Pin Excluding V _{CC} and V _{SS} | I | 10 | mA |
| 8 | Acceleration (without hitting internal g-cell stops) | 9 _{max} | ±800 | g |
| 9 | Powered Shock (six sides, 0.5 ms duration) | g _{pms} | ±1500 | g |
| 10 | Unpowered Shock (six sides, 0.5 ms duration) | 9 _{shock} | ±2000 | g |
| 11 | Drop Shock (to concrete surface) | h _{DROP} | 1.2 | m |
| 12 13 14 | Electrostatic Discharge Human Body Model (HBM) Charge Device Model (CDM) Machine Model (MM) | V _{ESD} V _{ESD} V _{ESD} | ±2000 ±500 ±200 | V V |
| 15 | Storage Temperature Range | T _{stg} | -40 to +125 | € |

Notes:

2.2 OPERATING RANGE

The operating ratings are the limits normally expected in the application and define the range of operation.

| Ref | Characteristic | Symbol | Min | Тур | Max | Units | |
|----------|--|-----------------|----------------------------------|--------------|----------------------------------|--------|------------|
| 16 17 | Supply Voltage Standard Operating Voltage, 3.3V operating range Standard Operating Voltage, 5V operating range | V _{CC} | V _L +3.15 +4.75 | +3.3 +5.0 | V _H +3.45 +5.25 | V V | (1) (1) |
| 18 | Operating Temperature Range | T _A | T _L -40 | _ | T _H +105 | С | (2) |

- 1. Characterized at all values of V_L and V_H . Production test is conducted at typical voltage unless otherwise noted.
- 2. Parameters tested 100% at final test.

^{1.} Verified by characterization, not tested in production.

2.3 **ELECTRICAL CHARACTERISTICS**

 $V_L \leq (V_{CC} - V_{SS}) \leq V_H, \, T_L \leq T_A \leq T_H, \, |\Delta T_A| < 4 \, \, \text{K/min unless otherwise specified}$

| Ref | Characteristic | Symbol | Min | Тур | Max | Units | |
|----------------------|---|--|------------------------------|--------------------------------|------------------------------|--------------------------------------|--------------------------------------|
| 19 | Supply Current Drain Analog-only output configuration | I _{DD} | | _ | 9.0 | mA | (1) |
| 20 21 22 23 | Power-On Recovery Threshold (See Figure 2-1) VCC CREG CREGA CREF | V _{POR_N} V _{POR_N} V _{POR_N} V _{POR_N} | 2.77 1.80 2.18 1.11 | _ _ _ _ | 3.15 2.32 2.50 1.29 | V V V | (2) (2) (2) (2) |
| 24 25 26 27 | Power-On Reset Threshold (See Figure 2-1) $$V_{\rm CC}$$ $C_{\rm REG}$ $C_{\rm REGA}$ $C_{\rm REF}$ | V _{POR_} A V _{POR_} A V _{POR_} A V _{POR_} A | 2.77 1.80 2.18 1.11 | _ _ _ | 2.95 2.10 2.31 1.19 | V V V | (2) (2) (2) (2) |
| 28 29 30 31 | Hysteresis (VPOR_N - VPOR_A, See Figure 2-1) VCC CREG CREGA CREF | V _{HYST} V _{HYST} V _{HYST} V _{HYST} | 0 0 0 0 | | 388 300 261 150 | mV mV mV mV | |
| 32 | Minimum Functional Voltage (See Figure 2-1) | V _{DACU} | _ | | 2.0 | V | (2) |
| 33 34 35 | Internally Regulated Voltages C _{REG} C _{REGA} (3) C _{REF} * | V _{DD} V _{2.5} V _{REF} | 2.42 2.42 1.20 | 2.50 2.50 1.25 | 2.58 2.58 1.29 | V V V | (1) (1) (1) |
| 36 37 | External Filter Capacitor (C _{REG} , C _{REGA}) Value ESR (including interconnect resistance) | C _{REG} ESR | 800 — | 1000 | 200 | nF mΩ | (2) (2) |
| 38 | Power Supply Coupling (4) Analog output | | | See Figu | ure 2-2 | | (2) |
| 39 40 41 42 | Analog Sensitivity (X _{OUT} , Y _{OUT}) 20g Range 35g Range 50g Range 100g Range | ASENS | _ _ _ _ | 23.40 13.40 9.37 4.68 | _ _ _ _ | mV/V/g mV/V/g mV/V/g mV/V/g | (1)(5) (1)(5) (1)(5) (1)(5) |
| 43 44 | Sensitivity Error $T_A = 25 ^{\circ}\text{C} \qquad \qquad * \\ 40 ^{\circ}\text{C} \le T_A \le 105 ^{\circ}\text{C}$ | ΔSENS ΔSENS | -8 -8 | _ | +8 +8 | % % | (1)(5) (1)(5) |
| 45 Note | Offset at 0g Analog output (X _{OUT} , Y _{OUT}) * | A _{OUT} | 0.46 × V _{CC} | 0.5 × V _{CC} | 0.54 × V _{CC} | V | (1)(5) |

- 1. Parameters tested 100% at final test.
- 2. Verified by characterization, not tested in production.
- Tested at V_{CC} = V_L and V_{CC} = V_H.
 Power supply ripple at frequencies greater than 900 kHz should be minimized to the greatest extent possible.
- 5. Devices are trimmed at 100 Hz with 1000 Hz low-pass filter option selected.
- (#) Indicates a FSL significant parameter (CPK > 1.33).
- (*) Indicates a FSL critical parameter (CPK > 1.67).

2.3 ELECTRICAL CHARACTERISTICS (CONTINUED)

 $V_L \leq (V_{CC} - V_{SS}) \leq V_H, \, T_L \leq T_A \leq T_H, \, |\Delta T_A| < 4 \, \, \text{K/min unless otherwise specified}$

| Ref | Characteristic | Symbol | Min | Тур | Max | Units | |
|----------------------------|---|--|-----------------------------------|-----------------------------------|-----------------------------------|---------------------------------|---------------------------------|
| | Output value on overrange | | | | | | |
| 46 47 48 49 | 20g Range 35g Range 50g Range 100g Range | 9over 9over 9over 9over | +20.0 +35.0 +50.0 +100.1 | +20.9 +36.6 +52.1 +104.3 | +22.1 +38.7 +55.3 +110.5 | g g g | (3) (3) (3) (3) |
| | Output value on Underrange | | | | | | |
| 50 51 52 53 | 20g Range 35g Range 50g Range 100g Range | 9under 9under 9under 9under | -20.1 -35.1 -50.1 -100.3 | -20.9 -36.6 -52.2 -104.5 | -22.2 -38.8 -55.4 -110.7 | g g g | (3) (3) (3) (3) |
| | Maximum acceleration without saturation of internal circuitry | | | | | | |
| 54 | All ranges | 9 _{SAT} | -200 | _ | +200 | g | (3) |
| 55 | Nonlinearity | NL _{OUT} | -1 | _ | 1 | % FSR | (3) |
| 56 | Noise (1Hz-1kHz) | n _{SD} | _ | _ | 1.1 | mg/√Hz | (3) |
| 57 58 | Positive Self Test Output Change $(X_{OUT}, Y_{OUT}, analog)$ $T_A = 25 ^{\circ}\text{C}$ $-40 ^{\circ}\text{C} \leq T_A \leq 105 ^{\circ}\text{C}$ | ΔST ΔST | 10 10 | _ _ | 18 18 | % FS % FS | (1) (1) |
| 59 60 61 62 | Cross-Axis Sensitivity V _{ZX} V _{YX} V _{ZY} V _{XY} | V _{ZX} V _{YX} V _{ZY} V _{XY} | -4 -4 -4 -4 | _ _ _ _ _ | +4 +4 +4 +4 | % % % % | (3) (3) (3) (3) |
| 63 64 65 66 67 | DAC Characteristics (X_{OUT}, Y_{OUT}) Minimum Output Level, I_{OUT} = -200 μ A Maximum Output Level, I_{OUT} = 200 μ A Offset Error Gain Error Differential Nonlinearity Integral Nonlinearity | AV _{LOW} AV _{HIGH} OFST GERR DNL | | _ _ _ _ | 0.25 +0.2 +0.3 +2 | V V %FSR %FSR digit | (2) (2) (2) (2) (2) |
| 68 69 | $T_A = 25^{\circ}C$ $-40^{\circ}C \le T_A \le 105^{\circ}C$ | INL INL | -3 -3.5 | _ _ | +3 +3.5 | digit digit | (2) (3) |
| 70 71 | Output High Voltage STATUS (I_{Load} = -100 μ A) 3.15 V \leq (V_{CC} - V_{SS}) \leq 3.45 V 4.75 V \leq (V_{CC} - V_{SS}) \leq 5.25 V | V _{OH} V _{OH} | 3.25 3.75 | = | _ | V V | (2) (2) |
| | Output Low Voltage STATUS ($I_{Load} = 100 \mu A$) 3.15 V \leq ($V_{CC} - V_{SS}$) \leq 3.45 V 4.75 V \leq ($V_{CC} - V_{SS}$) \leq 5.25 V | V _{OL} | | | 0.4 0.4 | V V | (2) |
| 74 75 | Output Loading (STATUS) Load Resistance Load Capacitance | Z _{OUT} C _{OUT} | 47 — | | 35 | kΩ pF | (3) (3) |

- 1. Parameters tested 100% at final test.
- 2. Parameters tested 100% at unit probe.
- 3. Verified by characterization, not tested in production.

2.3 ELECTRICAL CHARACTERISTICS (CONTINUED)

 $V_L \leq (V_{CC} - V_{SS}) \leq V_H, \, T_L \leq T_A \leq T_H, \, |\Delta T_A| < 4 \, \, \text{K/min unless otherwise specified}$

| Ref | Characteristic | Symbol | Min | Тур | Max | Units | |
|----------------------|---|--------------------------------------|------------------|------------------|--------------------|----------------|-------------------|
| 76 77 | Output Loading (X _{OUT} , Y _{OUT}) Load Resistance Load Capacitance | Z _{OUT} C _{OUT} | 25 — | _ _ | <u> </u> | kΩ pF | (3) (3) |
| | Input High Voltage RESET, SCLK, ST, $\overline{\text{CAP}}/\text{HOLD}$ 3.15 V \leq (V _{CC} - V _{SS}) \leq 3.45 V 4.75 V \leq (V _{CC} - V _{SS}) \leq 5.25 V | V _{IH} V _{IH} | 1.5 2.5 | _ | _ | V V | (2) (2) |
| | Input Low Voltage RESET, SCLK, ST, $\overline{\text{CAP}}/\text{HOLD}$ 3.15 V \leq (V _{CC} - V _{SS}) \leq 3.45 V 4.75 V \leq (V _{CC} - V _{SS}) \leq 5.25 V | V _{IL} V _{IL} | | | 0.85 1.0 | V V | (2) |
| 82 83 84 85 | Input Current High (at V _{IH}) SCLK, ST, CAP/HOLD V _{PP} /TEST (internal pulldown resistor) Low (at V _{IL}) RESET | I _{IH} R _{IN} | -30 190 30 | -50 270 50 | -260 350 260 | μΑ kΩ μΑ | (2) (2) (2) |

^{2.} Parameters tested 100% at unit probe.

^{3.} Verified by characterization, not tested in production.

2.4 CONTROL TIMING

 $V_L \leq (V_{CC} - V_{SS}) \leq V_H, \ T_L \leq T_A \leq T_H, \ |\Delta T_A| < 4 \ \text{K/min unless otherwise specified}$

| Ref | Characteristic | Symbol | Min | Тур | Max | Units | |
|----------|--|-----------------------|----------|---------|--------|-------------|------------|
| | DSP Low-Pass Filter (Note 9) Cutoff frequency (Note 10) | | | | | | |
| 86 | Filter Option \$0C, \$1F | f _{C(LPF)} | 380 | 400 | 420 | Hz | (7) |
| 87 | DSP Low-Pass Filter Cutoff frequency (-3dB, referenced to 0 Hz) Filter \$0C, \$1F | $f_{C(LPF)}$ | 335 | 353 | 371 | Hz | (7) |
| 88 | Filter Order Filter \$00 - \$12 | O _{LPF} | _ | 4 | _ | 1 | (7) |
| 89 | Power-On Recovery Time Power applied to X _{OUT} , Y _{OUT} valid | t _{XY} | | _ | 10 | ms | (1) |
| 90 | Internal Oscillator Frequency | fosc | 3.8 | 4.0 | 4.2 | MHz | (1) |
| 91 | Clock Monitor Threshold | f _{MON} | 3.6 | _ | 4.4 | MHz | (7) |
| 92 | Chip Select to Internal Reset (See Figure 2-3) | t _{CSRES} | 486 | 512 | 538 | μS | (7) |
| 93 94 | DAC Low-Pass Filter Number of Poles Cutoff Frequency | nPOLES f _C | <u> </u> | 1 10 | 20 | unit kHz | (1) (7) |
| 95 | Sensing Element Rolloff Frequency (-3 dB) | BW _{GCELL} | _ | 3 | _ | kHz | (1) |

- 1. Parameters tested 100% at final test.
- 2. Parameters tested 100% at unit probe.
- 3. Verified by characterization, not tested in production.
- 4. (*) Indicates a FSL critical parameter (CPK > 1.67). (#) Indicates a FSL significant parameter (CPK > 1.33).
- 7. Functionality verified 100% via scan. Timing characteristic is directly determined by internal oscillator frequency.
- 9. Devices are trimmed at 100 Hz with 1000 Hz low-pass filter option selected.
- Low-pass filter characteristics match those of other Freescale accelerometer devices. Cutoff frequencies shown are -4dB referenced to 0 Hz response, to correspond with previous specifications.

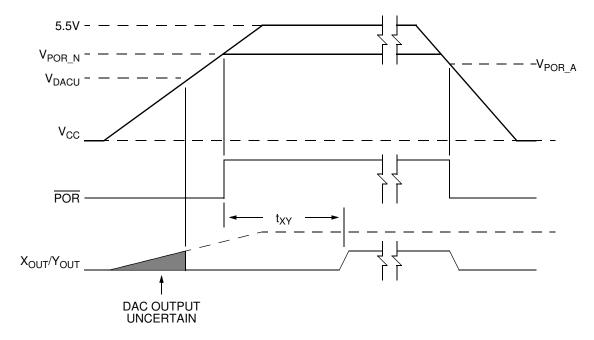


Figure 2-1 Power-Up Timing

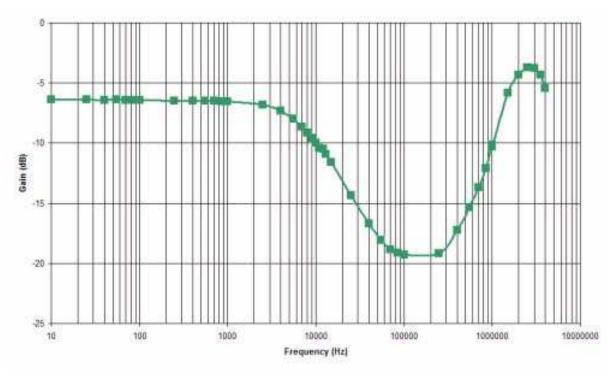


Figure 2-2 Power Supply Coupling - DAC Outputs

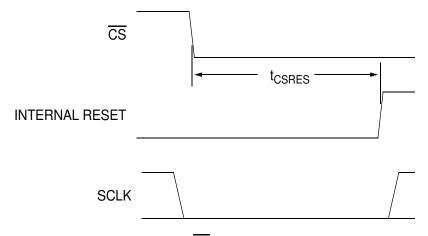
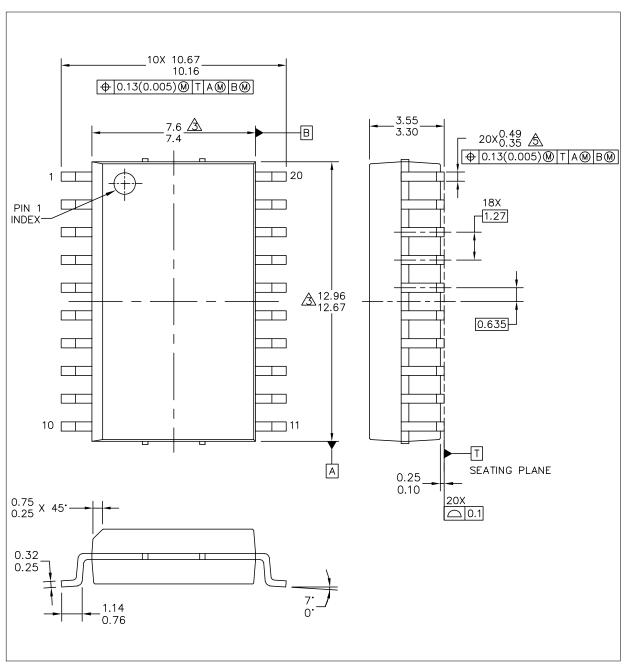


Figure 2-3 CS Reset Timing

PACKAGE DIMENSIONS



| © FREESCALE SEMICONDUCTOR, INC. ALL RIGHTS RESERVED. MECHANICAL | | L OUTLINE | PRINT VERSION NO | T TO SCALE |
|--|--|-------------------------------|------------------|-------------|
| 20LD SOIC W/B, 1.27 PITCH 7.5 X 12.8, ACCLEROMETER | | DOCUMENT NO: 98ASB17933C REV: | | REV: C |
| | | CASE NUMBER | 2: 475A-02 | 06 JUL 2006 |
| | | STANDARD: NO | N-JEDEC | |

PACKAGE DIMENSIONS

NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.
- 2. DIMENSIONS ARE IN MILLIMETERS.
- THIS DIMENSION DO NOT INCLUDE MOLD PROTRUSION.
- 4. MAXIMUM MOLD PROTRUSION 0.15(0.006) PER SIDE.
- THIS DIMENSION DOES NOT INCLUDE DAM BAR PROTRUSION ALLOWABLE DAM BAR PROTRUSION SHALL BE 0.13(0.005) TOTAL IN EXCESS OF THIS DIMENSION AT MAXIMUM MATERIAL CONDITION.

| © FREESCALE SEMICONDUCTOR, INC. ALL RIGHTS RESERVED. | MECHANICA | L OUTLINE | PRINT VERSION NO | OT TO SCALE |
|--|-----------|--------------|------------------|-------------|
| TITLE: 20LD SOIC W/B, 1. | 27 PITCH | DOCUMENT NO |): 98ASB17933C | REV: C |
| 7. 5 X 12. 8, ACCLEROMETER CASE-OUTLINE | | | R: 475A-02 | 06 JUL 2006 |
| | | STANDARD: NO | N-JEDEC | |

MMA6222AKEG

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